

ST13007

High voltage fast-switching NPN power transistor

Features

- DC current gain classification
- High voltage capability
- Low spread of dynamic parameters
- Very high switching speed

Applications

- Electronic ballast for fluorescent lighting
- Switch mode power supplies

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and high voltage capability.

It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

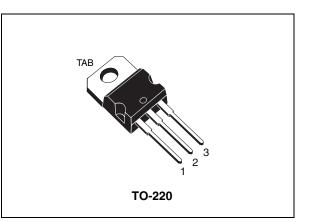


Figure 1. Internal schematic diagram

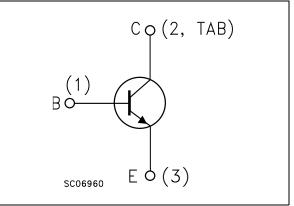


Table 1. Device summary

Order code	Marking ⁽¹⁾	Package	Packaging
ST13007	ST13007A	TO-220	Tube
3113007	ST13007B	10-220	Tube

1. The product is classified in DC current gain group A and group B, see *Table 5: hFE classification*. STM icroelectronics reserves the right to ship from any group according to production availability.

1 Electrical ratings

Table 2.	Absolute maximum ratings	

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	700	V
V _{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V _{EBO}	Emitter-base voltage ($I_C = 0$)	9	V
۱ _C	Collector current	8	А
I _{CM}	Collector peak current (t _P < 5 ms)	16	А
Ι _Β	Base current	4	А
I _{BM}	Base peak current (t _P < 5 ms)	8	А
P _{TOT}	Total dissipation at $T_c = 25 \ ^{\circ}C$	80	W
T _{STG}	Storage temperature	- 65 to 150	°C
Τ _J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case max	1.56	°C/W

2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 700 V V _{CE} = 700 V T _C = 125 °C			10 0.5	μA mA
I _{EBO}	Emitter cut-off current $(I_{\rm C} = 0)$	V _{EB} = 9 V			100	μA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage $(I_B = 0)$	I _C = 10 mA	400			v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage				1 2 3 3	V V V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage				1.2 1.6 1.5	V V V
h _{FE}	DC current gain	$I_{C} = 2 A \qquad V_{CE} = 5 V$ $I_{C} = 5 A \qquad V_{CE} = 5 V$			40 30	
t _s t _f	Resistive load Storage time Fall time	$V_{CC} = 300 V$ $I_C = 2 A$ $I_{B(on)} = -I_{B(off)} = 400 mA$ $T_P = 30 \ \mu s$	3		4.5 350	µs ns
t _s t _f	Inductive load Storage time Fall time			1.5 40	2.5 110	µs ns
t _s t _f	Inductive load Storage time Fall time			2 70		µs ns

Table 4. Electrical characteristics

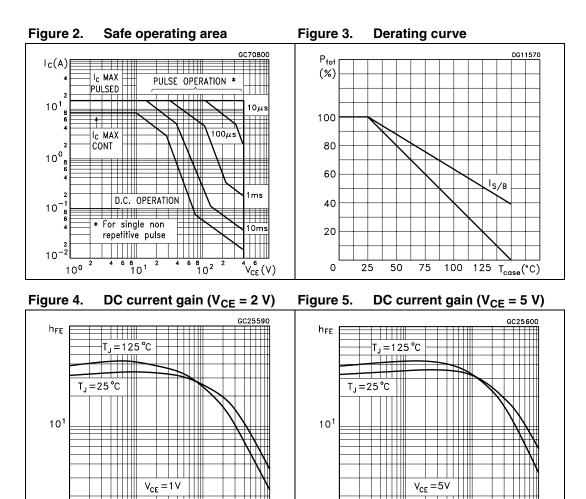
1. Pulse test: pulse duration \leq 300 µs, duty cycle \leq 2 %

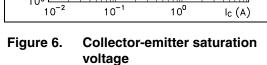
Table 5.	h _{FE} classification

Symbol	Parameter	Group	Min.	Max.	Unit
b	DC current gain	А	16	30	
h _{FE}	$I_{C} = 2 \text{ A}, V_{CE} = 5 \text{ V}$	В	26	40	

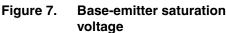


Electrical characteristics (curves) 2.1





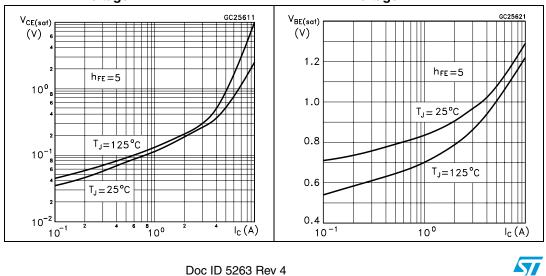
10⁰



10⁰

 $I_{C}(A)$

10⁻¹



100

10⁻²

Figure 8. Inductive fall time GC25640 t_f(ns) V_{Clamp}=250 V h_{FE}=5 $|_{B2} = -2|_{B1}$ $T_J = 125°C$ 10² T_J =25 °C 10¹ 0 2 4 $I_{C}(A)$ 1 3



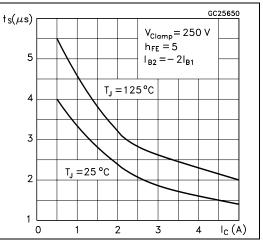
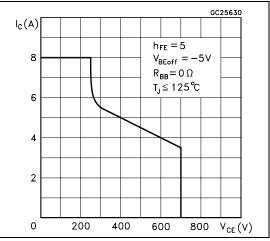


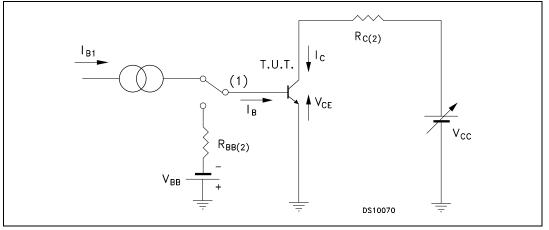
Figure 10. Reverse biased SOA





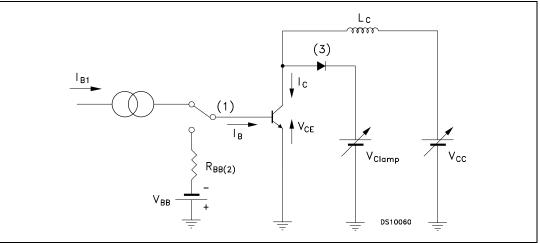
2.2 Test circuits





- 1. Fast electronic switch
- 2. Non-inductive resistor





- 1. Fast electronic switch
- 2. Non-inductive resistor
- 3. Fast recovery rectifier



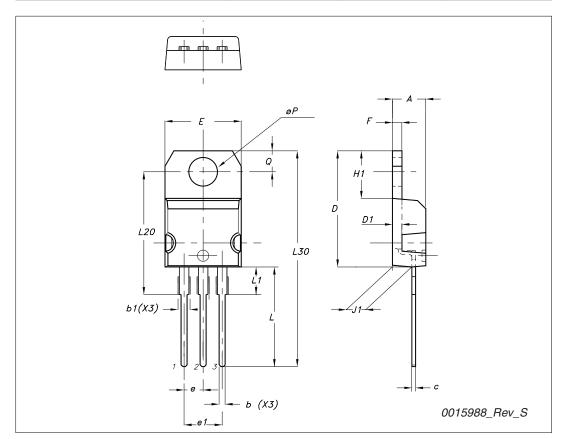
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.



	mm			
Dim				
	Min	Тур	Max	
A	4.40		4.60	
b	0.61		0.88	
b1	1.14		1.70	
С	0.48		0.70	
D	15.25		15.75	
D1		1.27		
E	10		10.40	
е	2.40		2.70	
e1	4.95		5.15	
F	1.23		1.32	
H1	6.20		6.60	
J1	2.40		2.72	
L	13		14	
L1	3.50		3.93	
L20		16.40		
L30		28.90		
ØP	3.75		3.85	
Q	2.65		2.95	





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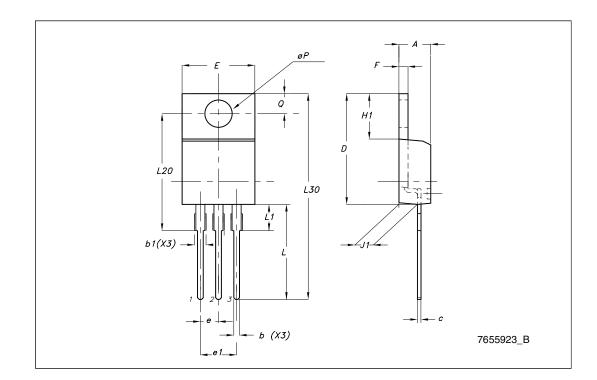


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Γ

TO-220 type E mechanical data				
DIM.		mm.		
	MIN.	ТҮР	MAX.	
A	4.47		4.67	
b	0.70		0.91	
b1	1.17		1.37	
с	0.31		0.53	
D	14.60		15.70	
E	9.96		10.36	
е		2.54		
e1	4.98	5.08	5.18	
F	1.17		1.37	
H1	6.10		6.80	
J1	2.52		2.82	
L	12.70		13.80	
L1	3.20		3.96	
L20	15.21		16.77	
øP	3.73		3.94	
Q	2.59		2.89	





4 Revision history

Table 6.Document revision history

Date	Revision	Changes
21-Jun-2004	3	Document migration, no content change.
16-Dec-2009	4	Updated TO-220 package mechanical data.



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